

Single Ultra-High speed and Wide Band Operational Amplifier

■ GENERAL DESCRIPTION

The **NJM2720** is single and ultra-high speed and wide band operational amplifier.

The NJM2720 is 250V/ μ s slew rate and 150ohm load drive is possible, at supply voltage of ± 2.5 V.

The NJM2720 is suitable for video signal processing, video line driver, video buffer, pulse amplifiers, ADC input buffer, measuring instrument, and digital communication.

■ PACKAGE OUTLINE

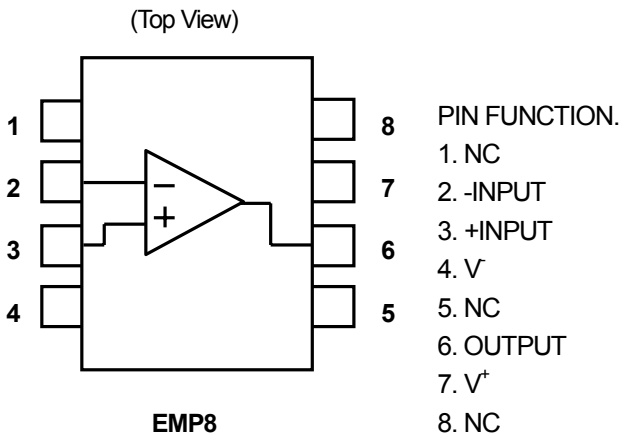


NJM2720E

■ FEATURES

- Operating Voltage : ± 2.5 V to ± 5.0 V
- Slew Rate : 250V/ μ s Typ. (at $V^+V^- = \pm 2.5$ V, $R_L = 150\Omega$)
- Unity-Gain : 120MHz Typ.
- Output Voltage : $V_{OH} = +1.4$ V Typ. (at $V^+V^- = \pm 2.5$ V, $R_L = 150\Omega$)
: $V_{OL} = -1.4$ V Typ. (at $V^+V^- = \pm 2.5$ V, $R_L = 150\Omega$)
- Offset Voltage : 1.5mV Typ.
- Operating Current : 9.0 mA Typ.
- Adequate phase margin : $\Phi_M = 60$ deg. Typ. (at $R_L = 2k\Omega$, voltage follower)
- Bipolar Technology
- Package Outline : EMP8

■ PIN CONFIGURATION



NJM2720

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺	11.0	V
Power Dissipation	P _D	EMP8 : 730 (Note1)	mW
Differential Input Voltage Range	V _{ID}	±3.0	V
Common Mode Input Voltage Range	V _{ICM}	11.0	V
Operating Temperature Range	T _{opr}	-40 to +85	°C
Storage Temperature Range	T _{stg}	-40 to +125	°C

(Note 1) On the PCB " EIA/JEDEC (76.2x11.43x1.6mm, four layers, FR-4) "

■ RECOMMENDED OPERATING CONDITION

(Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V ⁺ /V ⁻	±2.5 to ±5.0	V

■ ELECTRICAL CHARACTERISTICS

●DC CHARACTERISTICS

(V⁺/V⁻=±2.5V, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Current	I _{CC}	No Signal	-	9.0	15.0	mA
Input Offset Voltage	V _{IO}		-	1.5	16.0	mV
Input Bias Current	I _B		-	7.5	30.0	μA
Input Offset Current	I _{IO}		-	100	900	nA
Large Signal Voltage Gain	A _V	R _L =2kΩ	50	60	-	dB
Input Common Mode Voltage Range	V _{ICM}		+1.7 -1.2	+2.0 -1.5	- -	V V
Common Mode Rejection Ratio	CMR	-1.2V≤V _{ICM} ≤+1.7V	60	80	-	dB
Supply Voltage Rejection Ratio	SVR	±2.5V≤V ⁺ /V ⁻ ≤±5.0V	55	65	-	dB
Maximum Output Voltage Swing	V _{OM}	R _L =150Ω	±1.2	±1.4	-	V

●AC CHARACTERISTICS

(V⁺/V⁻=±2.5V, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Unity Gain Frequency	f _T	A _V =40dB, R _F =1.98kΩ R _G =20Ω, R _L =∞, C _L =5pF	-	120	-	MHz
Phase Margin	Φ _M	A _V =40dB, R _F =1.98kΩ R _G =20Ω, R _L =∞, C _L =5pF	-	60.0	-	Deg

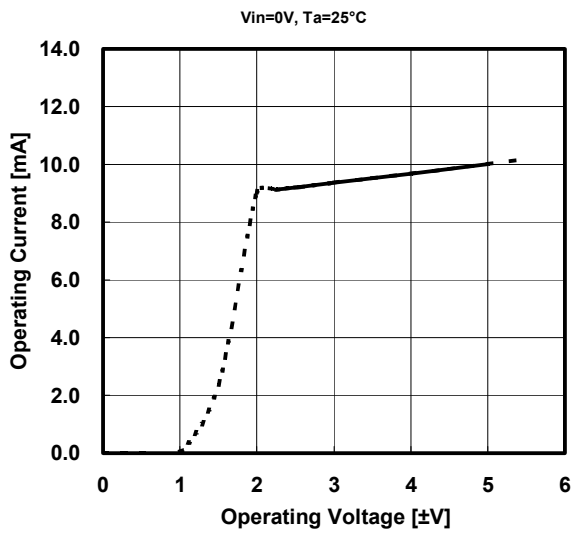
●AC CHARACTERISTICS

(V⁺/V⁻=±2.5V, Ta=25°C)

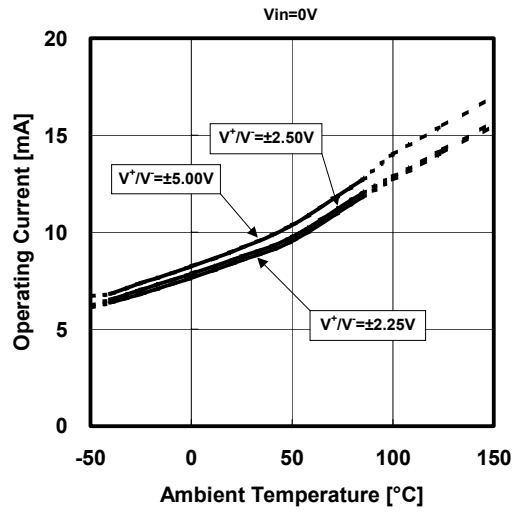
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	A _V =0dB, R _F =0Ω, R _G =∞ R _L =150Ω, C _L =5pF V _{IN} =2V _{PP}	-	250	-	V/μs

■ TYPICAL CHARACTERISTICS

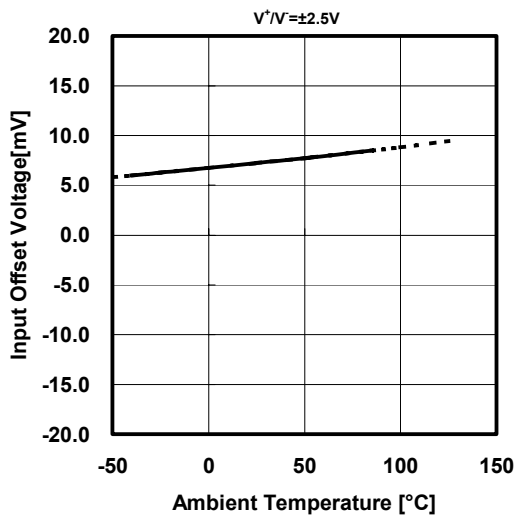
Operating Current vs. Operating Voltage



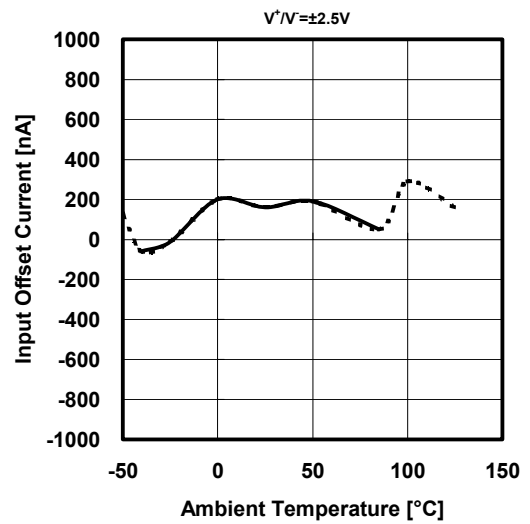
Operating Current vs. Ambient Temperature



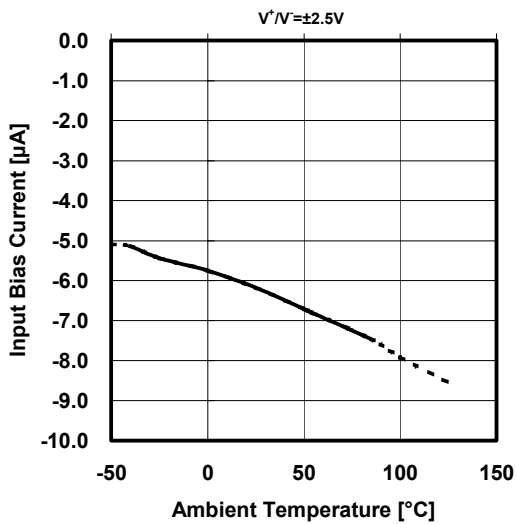
Input Offset Voltage vs. Ambient Temperature



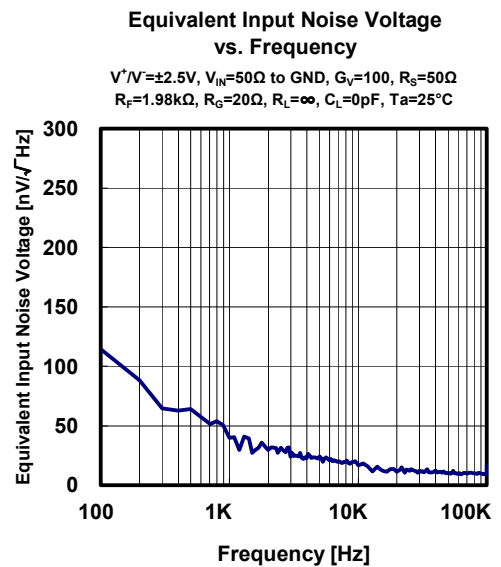
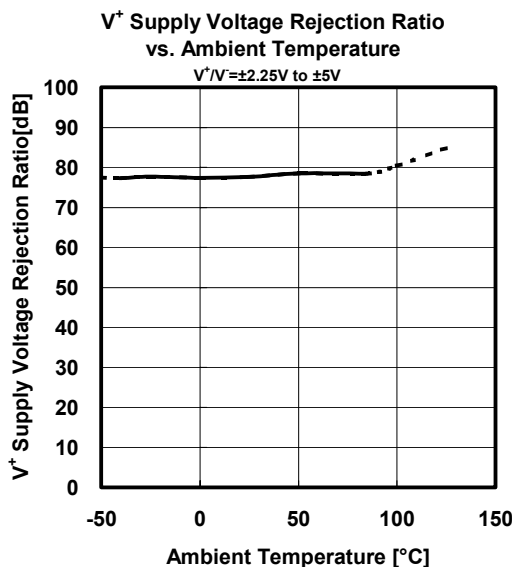
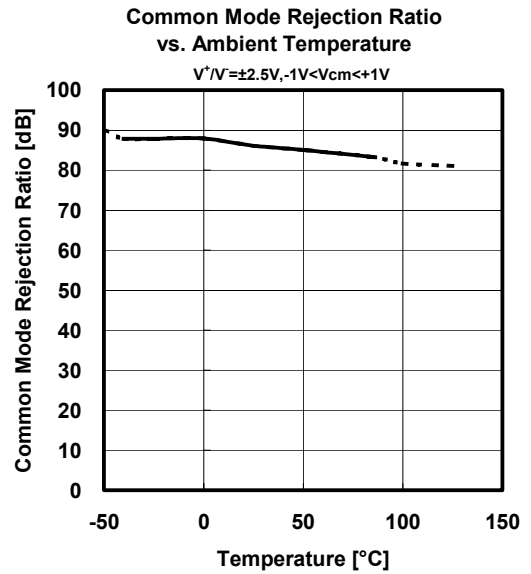
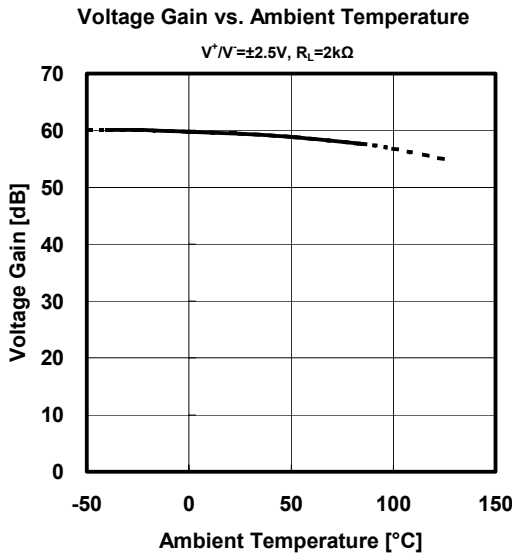
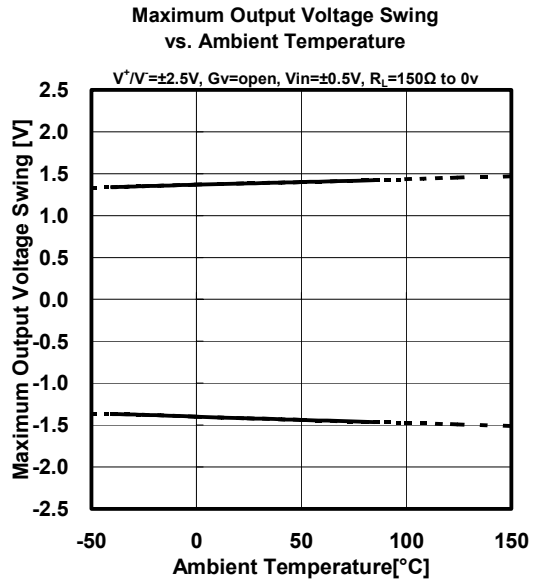
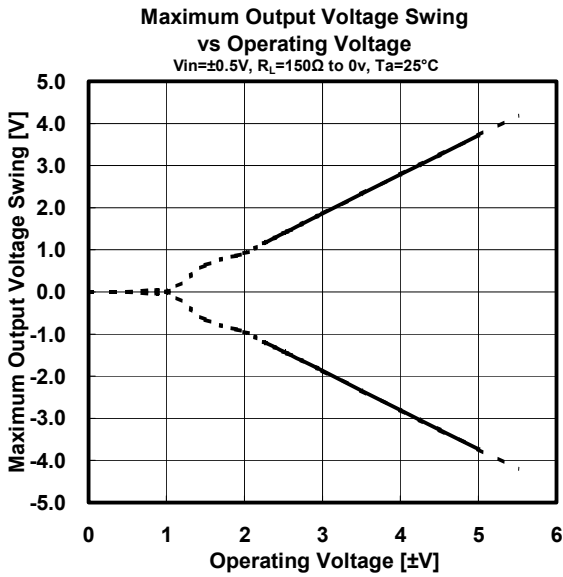
Input Offset Current vs. Ambient Temperature



Input Bias Current vs. Ambient Temperature

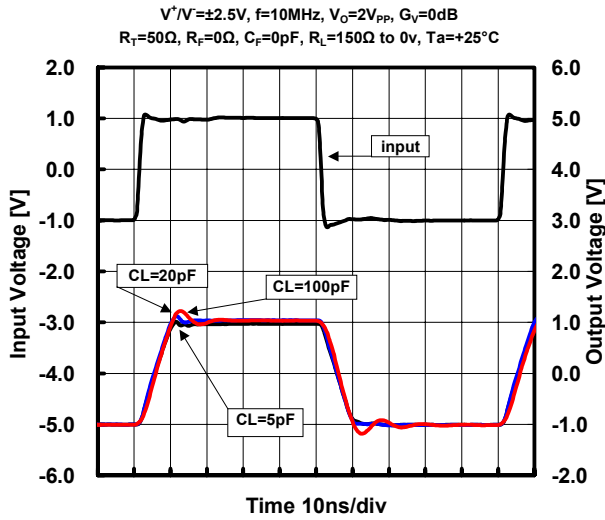


■ TYPICAL CHARACTERISTICS

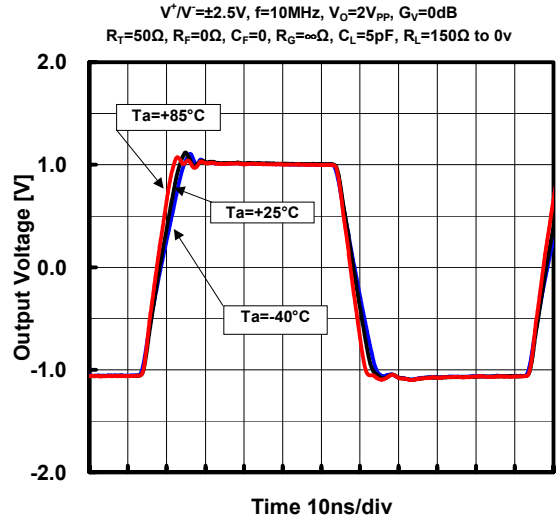


■ TYPICAL CHARACTERISTICS

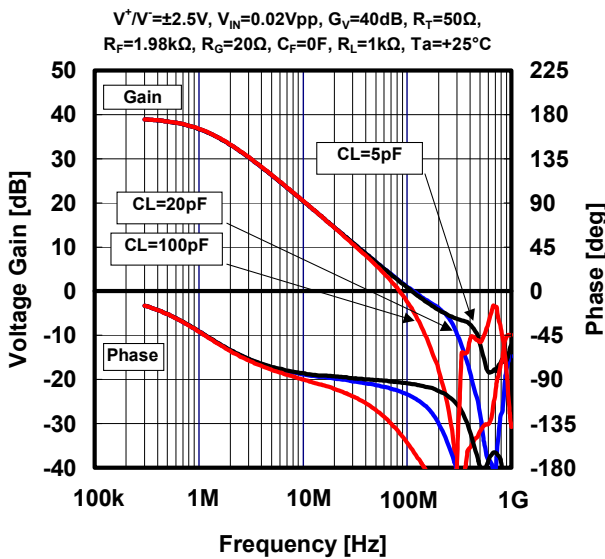
Pulse Response (with Capacitive load)



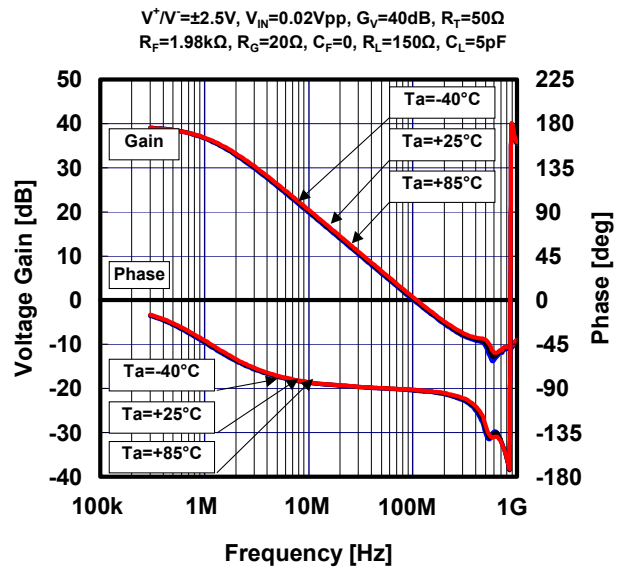
Pulse Response (correlation with T_a)



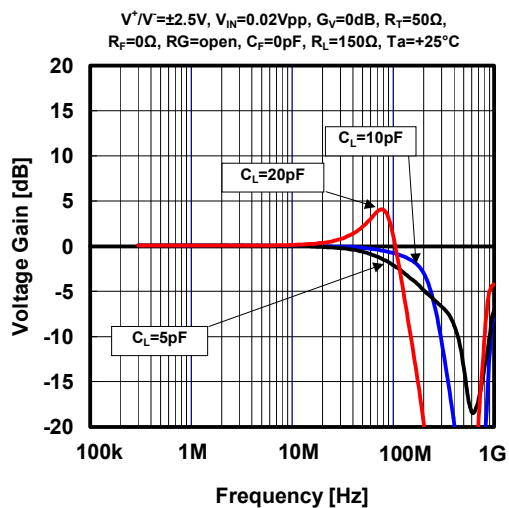
Voltage Gain vs. Frequency (with Capacitive Load)



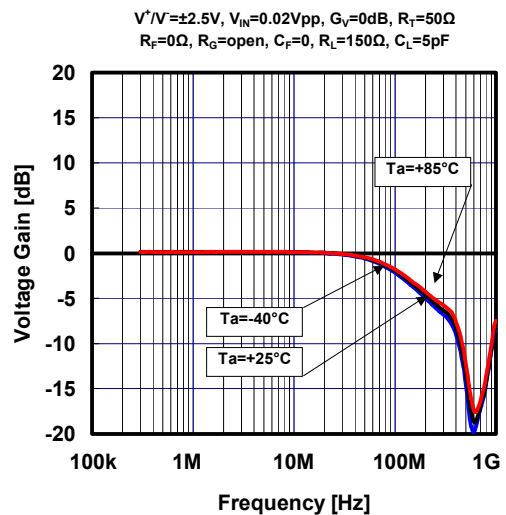
Voltage Gain vs. Frequency (correlation with T_a)



Voltage Gain vs. Frequency (with Capacitive Load)



Voltage Gain vs. Frequency (correlation with T_a)



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